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View Online at https://aerobasegroup.com/nsn/5961-01-194-4297

Inclosure Material:

Metal

Overall Length:

1.573 inches

Overall Height:

0.380 inches

Overall Width:

1.050 inches

Function For Which Designed:

Voltage regulator

End Application:

4935-00-178-0833

Mounting Facility Quantity:

2

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case and quality assurance level tx

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

189.0 regulator voltage

Current Rating Per Characteristic:

68.00 milliamperes source cutoff current horsepower metric

Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 unthreaded hole

Specification Data:

81349-mil-s-19500/114 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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